



# ADVANCED PRACTICAL PHYSICS Vol. II

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CCM K



*A Pragati Edition*

# CONTENTS

	An Introduction to Experimental Study of Electronics	1
	Section (A) : Semiconducting Diodes and Allied Two Electrode Devices	11
	Sectional Introduction :	13
<b>Expt. A1.</b>	Biasing a <i>pn</i> silicon or germanium-diode to plot and analyse :	14
	1. Forward bias characteristics	
	2. Reverse bias characteristics.	
<b>Expt. A2.</b>	To verify <i>pn</i> junction diode rectifier equation for a Si diode, say 1N4001, and to evaluate following parameters of interest :	17
	(a) Minority saturation current $I_0$	
	(b) Knee voltage $V_k$ .	
	(c) Energy band gap.	
<b>Expt. A3.</b>	To plot forward characteristics of a Ge point contact diode OA79 and to investigate the following objectives of interest :	20
	(a) To verify voltage loop equation, given below, and to find the internal resistance $R_i$ of the source $V_s$ .	
	$V_s = V_D + V_R + V_i \quad \dots (1)$	
	(b) To plot ( $V_D \propto V_R$ ) characteristics and to determine the knee voltage.	
	(c) To plot ( $V_D \propto V_R$ ) characteristics and show the dynamic behaviour of diode resistance $R_D$ .	
	(d) To plot ( $V_D \propto \log_{10} I$ ) characteristics in accordance with junction rectifier equation, given below, and to evaluate minority saturation current $I_0$ .	
	$I = I_0 \left[ \exp \left( \frac{eV}{kT} \right) - 1 \right] \quad \dots (2)$	
	(e) To infer the failure of ( $V_D \propto \log_{10} I$ ) variation in this case and to modify it to linear variation by plotting ( $\log_{10} V_D \propto \log_{10} I$ ).	
	(f) To employ ( $\log_{10} V_D \propto \log_{10} I$ ) variation to give the band gap of doped Ge used in OA79.	
<b>Expt. A4.</b>	To investigate forward characteristics of light emitting diode (LED) with following objectives :	24
	(a) To record the coordinates of the operating point of LED.	
	(b) To study the voltage regulation feature of LED characteristics.	
	(c) To study the dynamic behaviour of LED resistance $R_D$ .	
	(d) To employ junction rectifier equation to find the recombination energy as band gap of LED.	
<b>Expt. A5.</b>	To investigate the variation of reverse biased diode current ( $I_r$ ) with temperature and to evaluate the value of band gap of the intrinsic semiconductor used to make the diode in following cases :	27
	(a) Ge point contact diode OA79.	
	(b) Si junction diode 1N4001.	
	(c) Zener diode (Si).	
<b>Expt. A6.</b>	To investigate the forward and reverse characteristics of a zener diode and to accomplish following objectives :	30
	(a) Forward and reverse bias ( $V_z - I_z$ ) characteristics to evaluate knee	

- voltage, the variation of diode resistance  $R_D$  with voltage drop across the diode and thereby the voltage regulation.
- (b) Evaluation of energy  $E$  for forward and reverse characteristics by using junction rectifier equation, Wien's law and relate the values to the band gaps of doped and intrinsic semiconductor used to make the diode.
- (c) To study different forms of zener regulators.
- Expt. A7.** Investigation of voltage current characteristics of a tunnel diode to accomplish following objectives : 39
- (a) Regional analysis of ( $V - I$ ) characteristics to evaluate relaxation energy and other parameters of importance.
- (b) The use of tunnel diode as a relaxation oscillator and a switch.
- (c) The use of tunnel diode as ultra high frequency ( $uhf$ ) amplifier.
- Expt. A8.** To investigate the voltage current characteristics of following bidirectional solid state devices : 45
- (A) Diac : Two electrode ac switch.
- (B) Triac : Three electrode ac switch.
- (C) Few applications of diac and triac.
- Expt. A9.** To investigate the variation of junction capacitance of a silicon diode with reverse bias voltage by following methods. 49
- (a) Direct measurement by MIC 16H digital multimeter (DMM) or a capacitance meter.
- (b) By measuring ac voltage drop across reverse biased diode at different frequencies.
- Expt. A10.** To study the characteristics of following two electrode devices: 52
- (a) Schottky diode
- (b) Photoconductive diode
- (c) LDR and VDR or varistor
- (d) Thermistors
- (e) Pin diode
- Expt. A11.** To study the spectral characteristics of a photovoltaic cell and accomplish following objectives : 56
- (a) To evaluate the work function of the experimental photovoltaic cell.
- (b) To evaluate the value of universal Planck's constant  $h$ .
- (c) To prove Einstein's photoelectric equation as a result of (a) and (b).
- (d) To prove following two laws of radiation :
1. Wein's displacement law.
  2. Stefan's law.
- Expt. A12.** To investigate the rectifying action of SC diodes and dc power supplies in following sequential objectives : 63
- (a) The half and full wave rectification.
- (b) The use of reservoir capacitor as a filter.
- (c) The use of input capacitor  $\pi$  filter to smoothen and regulate the  $dc$  output.
- (d) The use of  $\pi$  filter and bleeder resistance to regulate  $dc$  output.
- (e) The use of a zener and a transistor as regulator in place a choke or  $\pi$  filter.
- (f) The use of bridge rectifier circuit in full wave rectification.
- (g) The dual polarity  $\pm V$  regulated supply.

<b>Expt. A12a.</b>	(1) To study a half wave rectifier.	65
	(2) To investigate the characteristics of full wave rectifier.	67
	(3) (a) To study a full wave rectifier with centre tapped transformer and $\pi$ filter.	68
	(b) To use a bleeder resistor to improve voltage regulation.	
	(4) To study a full wave bridge rectifier circuit.	70
	(5) (a) To rig up a single circuit with a CT transformer and SC diodes to study half and full wave rectification with T and $\pi$ filters.	71
	(b) The same as above but with an ordinary transformer and bridge rectifier : full wave rectification only.	
	(6) To study a regulated low voltage power supply.	73
	(7) To study a dual polarity $\pm V$ IC regulated power supply.	75
<b>Expt. A13.</b>	To study diode detection efficiency of SC diode by following methods:	76
	(a) Direct method.	
	(b) Load line method.	
<b>Expt. A14.</b>	To study following applications of SC diodes.	81
	(a) Diodes limiter or clipper circuits.	
	(b) Diode clamper circuits.	
<b>Expt. A15.</b>	To use diodes as following logic circuits :	86
	(a) An AND gate.	
	(b) An OR gate.	
	(c) Combined AND and OR gate.	
<b>SECTION 'B' : INTRODUCTION TO THREE ELECTRODE SEMICONDUCTING DEVICES</b>		
(i)	Sectional Introduction	95
<b>Expt. B1.</b>	To study the characteristics of <i>pnp</i> and <i>nnp</i> transistors in CB configurations with following objectives :	97
	(a) To plot input and output characteristics and evaluate input and output resistance and current gain $\alpha$ .	
	(b) To plot dc load line and dynamic characteristics and evaluate the output power, the second harmonic distortion and voltage gain.	
	(c) To plot the variation of $I_{CBO}$ with temperature.	
<b>Expt. B2.</b>	To study the characteristics of <i>pnp</i> and <i>nnp</i> transistors in CE configuration with following objectives :	104
	(a) To plot input and output characteristics and evaluate input and output resistance and current gain $\beta$ .	
	(b) To plot dc load line and dynamic characteristics and evaluate current gain ( $A_i$ ), voltage gain ( $A_v$ ), power gain ( $A_p$ ), output power ( $P_0$ ) and % distribution ( $D$ ).	
	(c) To investigate the variation of $I_{CEO}$ with temperature.	
<b>Expt. B3.</b>	To study the characteristics of a transistor in common collector configuration.	113
<b>Expt. B4.</b>	To determine hybrid parameters of a transistor by following methods:	116
	(a) By using low frequency input as source in case of CE circuit.	
	(b) By extrapolation of static characteristics of a transistor.	
<b>Expt. B5.</b>	The graphical load line method to analyse a CE amplifier with objectives to plot :	122

- (a) DC load line.  
(b) AC load line.
- Expt. B6.** To study different transistor biasing circuits in CE configuration :  
 (1) Fixed bias circuit  
 (2) Collector to base bias circuit  
 (3) Bias circuit with emitter resistor  
 (4) Potential divider bias circuit  
 (5) Emitter bias circuit
- Expt. B7.** To study a CE amplifier circuit with following objectives :  
 (1) To determine the quiescent operating conditions.  
 (2) To plot overload characteristics.  
 (3) To plot and analyse the frequency response.  
 (4) To find input and output impedance and thereby the power gain.  
 (5) To investigate the phase response between input and output voltage.
- Expt. B8.** To study the characteristics of emitter follower circuit with following objectives :  
 (1) To trace circuits of emitter follower and note the components.  
 (2) To evaluate and determine quiescent operating point values.  
 (3) To determine the voltage gain at 1 kHz.  
 (4) To plot frequency response from 10 Hz to 1 MHz.  
 (5) To determine input, output impedance ( $Z_{in}$ ,  $Z_{out}$ ), power gain  $A_p$  and phase response at 1 kHz.
- Expt. B9.** To study the characteristics of a combination or paraphase amplifier with following objectives :  
 (1) To trace the circuit and determine the quiescent operating conditions.  
 (2) To investigate the relative overload characteristics.  
 (3) To investigate the relative frequency response at 1 kHz.  
 (4) To study the relative input and output impedance and the power gain of the amplifiers.  
 (5) To study the relative phase response.
- Expt. B10.** To study the negative current feedback CE amplifier circuits with following objectives :  
 (1) To trace and explain the circuit.  
 (2) To decide and verify the quiescent operating conditions.  
 (3) To investigate the overload characteristics at 1 kHz.  
 (4) To study the frequency response and evaluate bandwidth (BW).  
 (5) To determine the input and the output impedance and thereby the power gain.  
 (6) To study the phase response.
- Expt. B11.** To study a two stage RC coupled CE amplifier circuit with following objectives:  
 (1) To trace the circuit and assign componentwise working.  
 (2) To evaluate operating conditions and experimentally test them.  
 (3) To plot stagewise overload characteristics at 1 kHz and explain the effect of coupling on stage gain.  
 (4) To investigate the frequency response of amplifier and compare it with the response of the single stage amplifier.  
 (5) To explain the experimental findings.

- Expt. B12.** To study a single ended LC and transformer coupled CE power amplifier with following objectives : 174
- To trace and explain the selection of circuit elements.
  - To evaluate the dc operating conditions.
  - To investigate the overloading of the amplifier.
  - To investigate the variation of output power with load impedance.
  - To determine input and output impedance and power gain.
- Expt. B13.** To study a pushpull transistorised power amplifier with following objectives : 182
- To trace the circuit and note the specific values.
  - To evaluate the dc operating conditions by experiment and theory.
  - To investigate the overload characteristics of amplifier at 1 kHz.
  - Evaluation of ac load in output,  $P_{ac}$ ,  $P_{dc}$  and amplifier efficiency by load line analysis.
  - To measure the distortion in the output at optimum load.
  - To record comments on single ended and pushpull system; classes A, B, C power amplification, the advantages of pushpull arrangement and load line analysis, value version of pushpull phase inverter circuit, complementary symmetry circuit.
- Expt. B14.** To study a tuned CE amplifier circuit with following objectives : 195
- Evaluation and experimental test of Q conditions.
  - Evaluation of resonant frequency of tuned circuit and its experimental test. Evaluation of capacitive reactance of coupling capacitors and  $C_E$ .
  - Frequency and phase response of the amplifier.
  - Determination of input and output impedance at resonant frequency and corresponding power gain.
- Expt. B15.** To study a differential amplifier (DA) with following objective : 200
- The amplitude and phase of output waves with respect to the input wave in case of a single ended differential amplifier.
  - The output waveforms in relation to two  $180^\circ$  phased input signals : the differential mode (DM) of DA.
  - The output waveforms of a DA for common mode (CM).
- Expt. B16.** To plot characteristics of a N-channel junction field effect transistor JFET (BFW10) and investigate the FET parameters. 207
- Expt. B17.** To study a FET differential amplifier circuit with objectives to use the circuit as a voltmeter of very high Ohm per volt for measuring either ac or dc voltage. 213
- Expt. B18.** To study a MOSFET common-source amplifier with following preliminary objectives : 215
- Enhancement type MOSFET
  - Depletion type MOSFET
  - Drain characteristics of an  $n$ -channel MOSFET
  - Biasing arrangements for JFETs
  - MOSFET common-source amplifier.
- Expt. B19.** To study following FET amplifier circuits : 220
- RC coupled common-source single stage FET amplifier
  - Two stage RC coupled common-source FET amplifier.
  - Series voltage negative feedback FET amplifier.
  - Single tuned FET amplifier.

- Expt. B20.** To study a unijunction transistor with following objectives :  
 (a) The characteristics of UJT by using two battery biasing.  
 (b) UJT characteristics by alternate single battery circuit.  
 (c) UJT relaxation oscillator. 238
- Expt. B21.** To study a silicon controlled rectifier (SCR) with following objectives. 239  
 (a) The voltage-current characteristics of a SCR (dc operation).  
 (b) The voltage waveforms across the load in case of single SCR (half wave rectification) and a pair of SCRs (full wave rectification); the effect of dc and ac triggering on the output (ac operation).  
 (c) The use of two inverted SCRs in phase control of ac power.  
 (d) The study of a UJT controlled SCR time delay circuit.
- Expt. B22.** To study the dc characteristics of a triac and prove its equivalence to two inverted SCRs for controlled ac rectification. 238
- Expt. B23.** A study of phase shift RC circuit and its use as an oscillator. 239
- Expt. B24.** To study a Wein bridge oscillator circuit. 245
- Expt. B25.** To study a twin-T oscillator. 249
- Expt. B26.** To study a Hartley oscillator. 252
- Expt. B27.** To study Colpitts oscillator. 254
- Expt. B28.** To obtain square wave from sine wave by using a CE circuit. 258
- Expt. B29.** To study a Schmitt Trigger with following objectives : 261  
 (a) To determine the operating characteristics of a Schmitt trigger.  
 (b) To generate a square wave by using a transistorised Schmitt trigger with a sine wave.  
 (c) To investigate trip points of an opamp Schmitt trigger and study it.  
 (d) To study an opamp relaxation oscillator.
- Expt. B30.** To study transistorised relaxation oscillator circuits under following trade names : 268  
 (a) Astable or free running multivibrator.  
 (b) Monostable or single or one shot multivibrator.  
 (c) Bistable or two shot multivibrator or flip-flop.
- Expt. B31.** To study to 555 timer as : 274  
 (a) Monostable multivibrator  
 (b) Astable multivibrator  
 (c) Sawtooth or ramp wave generator  
 (d) Voltage controlled oscillator (VCO).
- Expt. B32.** To study mixers, modulators and demodulators with following objectives : 281  
 (a) To observe frequency difference ( $f_x \sim f_y$ ) out of a CE transistor amplifier used as a mixer.  
 (b) To use CE transistor circuit to give out an amplitude modulated wave and study it.  
 (c) To demodulate an AM signal by using an envelope detector.

## SECTION 'C' : LINEAR AND DIGITAL INTEGRATED CIRCUITS (ICs)

### Introduction 289

- Expt. C1.** To familiarise with the basics of an operational amplifier 741 as a linear IC 290  
 with following objectives :

- (1) Stages used in an op amp 741.
  - (2) Base diagrams and terminals of op amp 741.
  - (3) Negative feedback and its importance in case of op amp 741.
  - (4) Characteristics of op amp 741.
  - (5) The use of negative feedback network to use op amp as :
    - (a) Inverting amplifier.
    - (b) Non inverting amplifier.
    - (c) Buffer amplifier.
    - (d) Inverting voltage summer.
    - (e) Nullification of quiescent output voltage by input offset voltage. Second method of nullification by matching the impedance of inverting and non-inverting circuits.
- Expt. C2.** To determine input base currents ( $I_{b1}$  and  $I_{b2}$ ), input offset current ( $I_{b1} - I_{b2}$ ), input bias current  $[(I_{b1} + I_{b2})/2 = I_{av}]$ , input offset voltage, quiescent output voltage and reducing it to zero in case of op amp 741. 298
- Expt. C3.** To study slew rate and bandwidth of op amp 741. 301
- Expt. C4.** To study negative feedback op amp 741 as : 302
- (a) Inverting amplifier.
  - (b) Non-inverting amplifier (NI)
  - (c) Buffer or unity gain NI amplifier.
- Expt. C5.** To use op amp 741 as : 305
- (a) Inverting voltage summer
  - (b) Difference amplifier.
  - (c) High gain amplifier.
- Expt. C6.** To use op amp 741 as : 308
- (a) Voltage amplifier.
  - (b) Voltage to Current converter.
  - (c) Current to Voltage converter.
  - (d) Current Amplifier.
- Expt. C7.** To study the following uses of open loop op amp 741 : 311
- (a) Voltage comparator.
  - (b) Active half wave rectifier.
  - (c) Active peak detector.
  - (d) Active positive limiter or clipper.
  - (e) Active clamper.
- Expt. C8.** To study following active filter circuits using op amp 741 : 315
- (a) Low pass active filter of first order.
  - (b) Low pass active filter of second order.
  - (c) High pass active filter of second order.
  - (d) Active notch filter or twin T-filter.
- Expt. C9.** Use of op amp 741 to measure differential voltage by : 321
- (a) Single op amp 741.
  - (b) Three op amps 741 (Instrumentation amplifier)
- Expt. C10.** To study overload and frequency response characteristics of following IC 323 amplifier.
- (a) LM380, LM308, LM741 and quadrupled op amp LM324.



- (b) Power IC amplifier TBA810.
- Expt. C11.** To study IC8038 as a sine, square and triangular wave generator. 328
- Expt. C12.** An elementary study of IC723 as voltage and current regulator. 329
- Expt. C13.** An experimental study of following op amp based oscillator circuits to produce 331  
sine, square and sawtooth or triangular waves.
- Phase shift oscillator : Sine wave
  - Wein bridge oscillator : Sine wave
  - Twin - T oscillator : Sine wave
  - Schmitt trigger : Square wave generator by using sine wave as input.
  - Relaxation oscillator : Square wave generator by using input sawtooth wave of RC circuit is input.
  - Op amp integrator : Sawtooth wave generator by using square wave as input.
- Expt. C14.** An experimental study of IC555 timer as : 336
- Astable multivibrator or timer.
  - Monostable multivibrator or timer.
  - Voltage controlled oscillator (VCO).
  - Sawtooth wave oscillator.
- Expt. C15.** To familiarise with basics of digital electronics in following sequence: 341
- Binary numbers and their experimental realisation by electrical and electronic circuits.
  - Basic AND, OR and NOT operations. Derived NAND and NOR operations. Logic discrete circuits to work as AND, OR, NOT, NAND and NOR gates along with their symbols.
  - The IC gates as building blocks of digital electronics.
- Expt. C16.** An experiment to test IC gates by verifying the truth tables in following cases: 348
- Two input AND gate IC 7408.
  - Two input OR gate IC 7432.
  - Two input NAND gate IC SN 7400.
  - Three input NOR gate IC 7427. Its use as inverter or NOT gate. The hex inverter IC 7404.
  - Four input NAND gate IC SN 7420.
- Expt. C17.** An experimental study of following gate combinations : 354
- Combination of NOT and AND to form NAND.
  - Combination of NOT and OR to form NOR.
  - Combinations (i) AND-OR, (ii) OR-AND.
- Expt. C18.** To study binary addition with following objectives : 358
- Rules of binary addition and inter conversion of binary and decimal numbers.
  - Specific feature of exclusive - OR gate.
  - Binary half adder.
  - Binary full adder.
- Expt. C19.** To study flip-flops as the base of digital ICs with following sequential 367 objectives :
- Basic elements of flip-flops as digital binary or decade counters.
  - To construct RS flip-flops by NOR or NAND gates.

- (c) To study the working of D flip-flop.  
 (d) To study the working of edge-triggered D flip-flop.  
 (e) To study the working to JK flip-flop.
- Expt. C20.** An elementary study of digital binary counters using ICs (JK flip-flop 7476) : 379  
 (a) Basic elements of binary counters.  
 (b) To rig up a four bit binary up and down counter by using JK flip-flops 7476 and test it.  
 (c) To convert the above binary counter into a ring counter and Johnson counter and test them.
- Expt. C21.** To study phase locked loop (PLL) with following objectives : 385  
 (a) To adjust the free running frequency of a phase locked loop (PLL).  
 (b) To determine the lock range of PLL.  
 (c) To determine the capture range of PLL.  
 (d) To determine the dc output voltage from the frequency modulated (FM) output.

## SECTION 'D' : AUXILIARY SECTION ON BASIC ELECTRICAL MEASUREMENTS AND STATISTICAL CORRELATION OF EXPERIMENTAL OBSERVATIONS

### Sectional Introduction

- Expt. D1.** To set up an analog multimeter by using a micro-ammeter of range  $100 \mu\text{A}$  and use it as specified below : 393  
 (1) Multirange Ammeter of following ranges :  
 $100 \mu\text{A}$ , 1 mA, 10 mA, 100 mA and 1 A.  
 (2) Multirange Voltmeter of following ranges :  
 100 mV, 1 V, 10 V, 100 V and 1 kV.  
 (3) AC voltmeter and ammeter of different ranges.  
 (4) Ohm-meter of different ranges.
- Expt. D2.** An elementary know how about the electronic dc and ac voltmeters. 405  
 (a) Vacuum tube volt meter (VTVM)  
 (b) Transistorised and FET versions of VTVM  
 (c) Operational amplifier based voltmeter.  
 (d) AC measurement by these units and AC millivoltmeter.  
 (e) Use of analog moving coil or a digital voltmeter (DVM) at the output.  
 Measurement of resistance (R) and current (I) by such units.
- Expt. D3.** An experimental know-how about cathode ray oscillograph (CRO) to measure and study the following : 411  
 (1) To display an electro-magnetic waveform.  
 (2) To measure the following by CRO.  
 (a) The voltage amplitude of ac or dc.  
 (b) The frequency and the waveform.  
 (c) The relative phase of a wave.  
 (d) To measure current.  
 (e) To measure resistance-impedance.
- Expt. D4.** An elementary know-how about signal generators and their experimental applications. 421

